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0.2A surface mount Schottky diode

BAT54C2

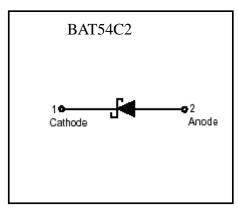
Features

- High current capability, low forward voltage drop
- High surge current capability
- Guardring for over voltage protection
- Low power loss, high efficiency
- Ultra high-speed switching
- Low profile surface mounted package in order to minimize board space

Mechanical data

- •Case : Molded plastic, SC-79/SOD523.
- •Epoxy : UL94-V0 rated flame retardant
- •Terminals : Plated terminals, solderable per MIL-STD-750 method 2026.
- •Polarity : Indicated by cathode band.
- •Mounting position : Any.

Symbol





Outline

Ordering Information

Device	Package	Shipping	
BAT54C2-0-T5-G	SOD-523 (Pb-free lead plating and halogen-free package)	8000 pcs / tape & reel	
	Environment friendly grade : S for RoHS compliant products, Green compound products	G for RoHS compliant and	
P	Packing spec, T5 : 8000 pcs / tape & reel, 7" reel		
P	roduct rank, zero for no rank products		
P	Product name		



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Absolute Maximum Ratings (TA=25°C, unless otherwise noted)

Parameters	Conditions	Symbol	Value	Units				
Repetitive peak reverse voltage		VRRM	30					
RMS voltage		VRMS	21	V				
Continuous reverse voltage		VR	30					
Forward rectified current		IF	0.2					
Repetitive Peak Forward Current		IFM	0.3	А				
Non-repetitive Peak Forward Current		I _{FSM}	0.6					
Total Device Dissipation	TA=25°C (Note)	PD	200	mW				
Thermal resistance	Junction to Ambient (Note)	$R_{\theta JA}$	625	°C/W				
Storage temperature range		Tstg	-65 ~ +175	°C				
Operating junction temperature range		Tj	-65 ~ +150	°C				

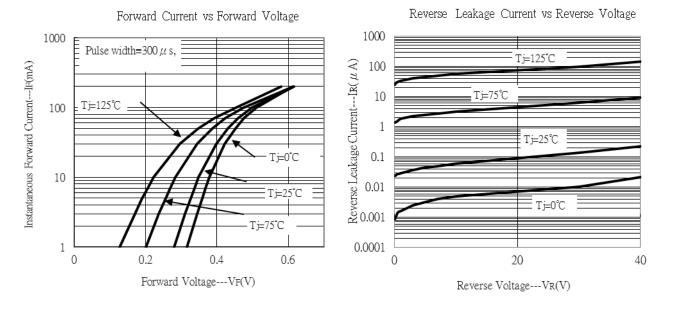
Note : When device mounted on FR-5 PCB with minimum pad.

Characteristics (TA=25°C)

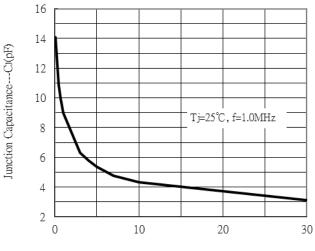
Characteristic	Symbol	Condition	Min.	Тур	Max.	Unit	
Reverse Breakdown Voltage	VBR	Ir=100µA	30	-	-	V	
	V _F 1	IF=0.1mA	-	-	240		
	VF2	IF=1mA	-	-	320		
Forward Voltage	VF 3	IF=10mA	-	-	400	mV	
	VF4	IF=30mA	-	-	500		
	VF 5	IF=100mA	-	-	800		
Reverse Leakage Current (Note 2)	Ir	Vr=30V	-	-	2	μΑ	
Diode Capacitance	Cd	Vr=1V, f=1MHz	-	-	10	pF	
Reverse Recovery Time	trr	IF=IR=10mA RL=100Ω measured at IR=1mA	-	-	5	ns	



Typical Characteristics

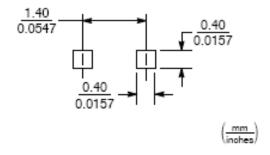


Junction Capacitance vs Reverse Voltage



Reverse Voltage---VR(V)

Recommended Footprint

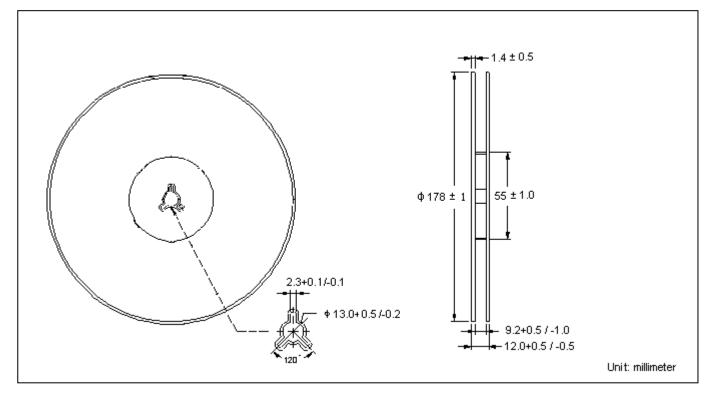




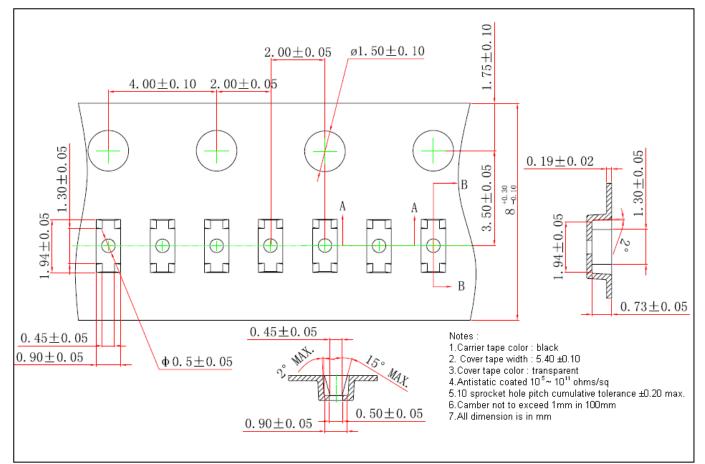
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Reel Dimension



Carrier Tape Dimension

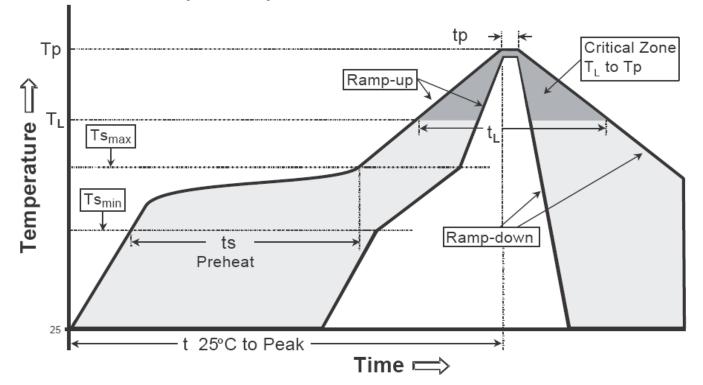




Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



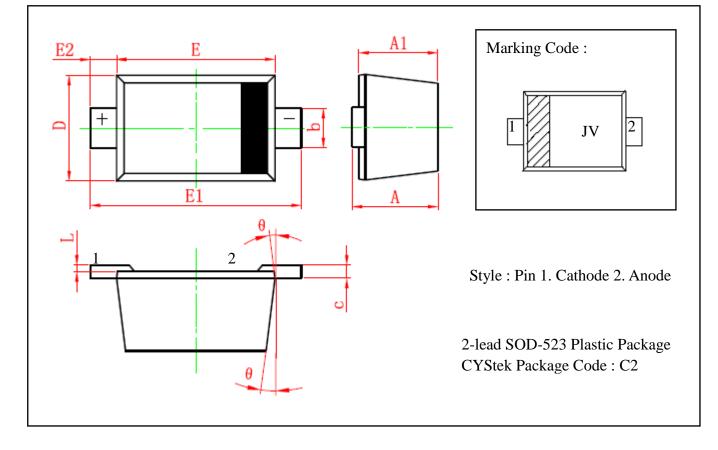
Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly		
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.		
Preheat				
-Temperature Min(Ts min)	100°C	150°C		
-Temperature Max(Ts max)	150°C	200°C		
-Time(ts min to ts max)	60-120 seconds	60-180 seconds		
Time maintained above:				
-Temperature (T∟)	183°C	217°C		
– Time (t∟)	60-150 seconds	60-150 seconds		
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C		
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds		
Ramp down rate	6°C/second max.	6°C/second max.		
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.		

Note : All temperatures refer to topside of the package, measured on the package body surface.



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SOD-523 Dimension



									*: Typical		
DIM	Millimeters		Inches		DIM	Millim	neters	Inc	nes		
DIIVI	Min.	Max.	Min.	Max.	Min.	Min.	Max.	Min.	Max.		
Α	0.510	0.770	0.020	0.031	E	1.100	1.300	0.043	0.051		
A1	0.500	0.700	0.020	0.028	E1	1.500	1.700	0.059	0.067		
b	0.250	0.350	0.010	0.014	E2	0.200 REF		0.008	REF		
С	0.080	0.150	0.003	0.006	L	0.010	0.070	0.001	0.003		
D	0.750	0.850	0.030	0.033	θ	7°REF		θ 7° REF		7 °	REF

Notes: 1.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 2.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead: Pure tin plated.

• Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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